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APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.
10/729,034	12/04/2003	Kuan-Lun Chang	67,200-1157	8853
TING & ASS	7590 04/25/2007 OCIATES	EXAMINER		
TUNG & ASSOCIATES Suite 120 838 W. Long Lake Road Bloomfield Hills, MI 48302			GARCIA, JOANNIE A	
			ART UNIT	PAPER NUMBER
Bloomine a 1111	113, 1411 40302		2823	
SHORTENED STATUTORY PERIOD OF RESPONSE		MAIL DATE	DELIVERY MODE	
2 MONITUS		04/25/2007	PAPER	

Please find below and/or attached an Office communication concerning this application or proceeding.

If NO period for reply is specified above, the maximum statutory period will apply and will expire 6 MONTHS from the mailing date of this communication.

	· ·	Application No.	Applicant(s)			
Office Action Summary		10/729,034	CHANG ET AL.			
		Examiner	Art Unit			
•		Joannie A. García	2823			
The MAILING DATE of this communication appears on the cover sheet with the correspondence address Period for Reply						
WHIC - Exter after - If NO - Failu Any r	ORTENED STATUTORY PERIOD FOR REPLY CHEVER IS LONGER, FROM THE MAILING DATE is used in the provisions of 37 CFR 1.13 SIX (6) MONTHS from the mailing date of this communication. Period for reply is specified above, the maximum statutory period were to reply within the set or extended period for reply will, by statute, reply received by the Office later than three months after the mailing and patent term adjustment. See 37 CFR 1.704(b).	ATE OF THIS COMMUNICATION (16(a). In no event, however, may a reply built apply and will expire SIX (6) MONTHS for cause the application to become ABANDO	ON. e timely filed rom the mailing date of this communication. DNED (35 U.S.C. § 133).			
Status						
2a)⊠	Responsive to communication(s) filed on This action is FINAL . 2b) This Since this application is in condition for allowar closed in accordance with the practice under <i>E</i>	action is non-final.	·			
Dispositi	on of Claims					
5)⊠ 6)⊠ 7)⊠	Claim(s) 1-7,10,11 and 22-32 is/are pending in 4a) Of the above claim(s) is/are withdraw Claim(s) 10 and 26-32 is/are allowed. Claim(s) 1,3,5-7,11,22,23 and 25 is/are rejecte Claim(s) 2,4 and 24 is/are objected to. Claim(s) are subject to restriction and/or	vn from consideration.				
Applicati	on Papers					
10)	The specification is objected to by the Examine The drawing(s) filed on is/are: a) access Applicant may not request that any objection to the Replacement drawing sheet(s) including the correct The oath or declaration is objected to by the Example 2.	epted or b) objected to by the drawing(s) be held in abeyance. ion is required if the drawing(s) is	See 37 CFR 1.85(a). objected to. See 37 CFR 1.121(d).			
Priority u	ınder 35 U.S.C. § 119					
 12) Acknowledgment is made of a claim for foreign priority under 35 U.S.C. § 119(a)-(d) or (f). a) All b) Some * c) None of: 1. Certified copies of the priority documents have been received. 2. Certified copies of the priority documents have been received in Application No. 3. Copies of the certified copies of the priority documents have been received in this National Stage application from the International Bureau (PCT Rule 17.2(a)). * See the attached detailed Office action for a list of the certified copies not received. 						
Attachmen	t(s) e of References Cited (PTO-892)	4) 🔲 Interview Summ	200/ /PTO 413)			
2) Notice 3) Information	te of References Cited (PTO-692) te of Draftsperson's Patent Drawing Review (PTO-948) mation Disclosure Statement(s) (PTO/SB/08) tr No(s)/Mail Date	Paper No(s)/Ma				

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The text of those sections of Title 35, U.S. Code not included in this action can be found in a prior Office action.

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Claims 1, 3, 5-7, 11, 22, 23, and 25, are rejected under 35 U.S.C. 102(e) as being anticipated by Kiyotoshi (US 2004/0152258 A1).

The rejection is maintained as stated in the Office Action mailed 01-04-07, and as stated below.

Kiyotoshi discloses a first MIM capacitor structure disposed in a first IMD layer 213 comprising a first upper electrode 204a and a first lower electrode 202a (Figures 17-18), at least a second MIM capacitor structure arranged in stacked relationship in an overlying IMD layer 214 comprising a second upper electrode 210a and second lower electrode 208a separate from said first upper and first lower electrodes to form an MIM capacitor stack (Figures 17-18), wherein a lowermost MIM capacitor structure is formed in an IMD layer greater than about the second IMD layer formed over a semiconductor wafer (Figures 17-18), wherein, the first lower electrode is arranged in common electrical signal communication comprising electrically communicating vias with the second upper electrode and the first upper electrode is arranged in common electrical signal communication with the second lower electrode to form said MIM capacitor stack in parallel electrically relationship (Figure 18, and Paragraph 0082), wherein the respective upper and lower electrodes comprise a metal selected from the group consisting of Al, Cu, Ta, Ti, and nitrides that comprise silicided nitrides thereof (Paragraphs 0049 and 0066), wherein a respective lower electrode of a respective MIM capacitor structure has a width dimension greater than a respective upper electrode (Figure 17), and wherein the upper electrodes including

electrically communicating metal filled vias of the respective MIM structures in the MIM capacitor stack comprise a substantially identical structure (Figure 18), a tantalum oxide capacitor dielectric sandwiched between the respective upper and lower electrodes (Figure 18, and Paragraph 0071), and respective upper and lower electrodes comprise TiN, or TaN (Paragraph 0066).

Applicant argues that Kiyotoshi et al does not teach a first and second IMD layers, first lower and upper electrodes in the first IMD layer and the second layer and upper electrodes separate from the first lower and upper electrodes in the overlying IMD layer. However, Hiyotoshi et al discloses a first and second IMD layers 213/214, first lower and upper electrodes 202a/204a in the first IMD layer and the second layer and upper electrodes separate from the first lower and upper electrodes in the overlying IMD layer, as shown in Figures 17 and 18, and as disclosed in Paragraphs 0079, 0066, and 0082.

Claims 2, 4, and 24, are objected to as being dependent upon a rejected base claim, but would be allowable if rewritten in independent form including all of the limitations of the base claim and any intervening claims.

Claims 10, and 26-32, are allowed.

THIS ACTION IS MADE FINAL. Applicant is reminded of the extension of time policy as set forth in 37 CFR 1.136(a).

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A shortened statutory period for reply to this final action is set to expire THREE MONTHS from the mailing date of this action. In the event a first reply is filed within TWO MONTHS of the mailing date of this final action and the advisory action is not mailed until after the end of the THREE-MONTH shortened statutory period, then the shortened statutory period will expire on the date the advisory action is mailed, and any extension fee pursuant to 37 CFR 1.136(a) will be calculated from the mailing date of the advisory action. In no event, however, will the statutory period for reply expire later than SIX MONTHS from the mailing date of this final action.

Any inquiry concerning this communication or earlier communications from the examiner should be directed to Joannie García whose telephone number is (571) 272-1861. The examiner can normally be reached on Monday through Friday.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Matthew Smith, can be reached on (571) 272-1907. The fax phone number for the organization where this application or proceeding is assigned is 571-273-8300.

Information regarding the status of an application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for published applications may be obtained from either Private PAIR or Public PAIR. Status information for unpublished applications is available through Private PAIR only. For more information about the PAIR

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system, see http://pair-direct.uspto.gov. Should you have questions on access to the Private PAIR system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free).

George Fourson Primary Examiner Art Unit 2823

JAG

April 12, 2007

GFourson

Primary Examiner